COMPLIANT



Vishay Siliconix

# **Buffered H-Bridge Driver with Integrate MOSFET**

#### **DESCRIPTION**

The Si9986 is an integrated, buffered H-bridge with TTL compatible inputs and the capability of delivering a continuous 1 A at  $V_{DD}$  = 12 V (room temperature) at switching rates up to 200 kHz. Internal logic prevents the upper and lower outputs of either half-bridge from being turned on simultaneously. Unique input codes allow both outputs to be forced low (for braking) or forced to a high impedance level.

The Si9986 is available in both standard and lead (Pb)-free, 8-pin SOIC packages, specified to operate over a voltage range of 3.8 V to 13.2 V, and the commercial temperature range of 0 °C to 70 °C (C suffix) and the industrial temperature range of - 40 °C to 85 °C (D suffix).

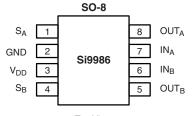
#### **FEATURES**

- 1 A H-bridge
- 200 kHz switching rate
- Shoot-through limited
- TTL compatible inputs
- 3.8 V to 13.2 V operating range
- Surface mount packaging

## **APPLICATIONS**

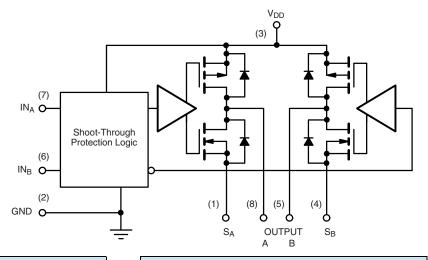
- VCM driver
- Brushed motor driver
- Stepper motor driver
- Power converter
- Optical disk drives
- Power supplies
- High performance servo

### FUNCTIONAL BLOCK DIAGRAM, PIN CONFIGURATION AND TRUTH TABLE



Top View

TRUTH TABLE					
INA	IN <sub>B</sub>	OUTA	OUTB		
1	0	1	0		
0	1	0	1		
0	0	0	0		
1	1	HiZ	HiZ		



PIN DESCRIPTION				
Pin Number	Name	Function		
1	S <sub>A</sub>	Source of the low-side MOSFET on bridge arm A		
2	GND	Ground		
3	$V_{DD}$	IC power supply		
4	S <sub>B</sub>	Source of the low-side MOSFET on bridge arm B		
5	OUTB	Center tap of bridge arm B. Connects to one end of the load		
6	IN <sub>B</sub>	Input signal to control bridge arm B		
7	IN <sub>A</sub>	Input signal to control bridge arm A		
8	OUT <sub>A</sub>	Center tap of bridge arm A. Connects to the other end of the load		

ORDERING INFORMATION					
Part Number	Temperature Range	Package			
Si9986CY-T1	0 °C to 70 °C	Tape and reel			
Si9986DY-T1	- 40 °C to 85 °C	Tape and Teel			
Si9986CY-T1-E3	0 °C to 70 °C	Lead (Pb)-free			
Si9986DY-T1-E3	- 40 °C to 85 °C	Tape and reel			
Si9986CY	0 °C to 70 °C	Bulk (tubes)			
Si9986DY	- 40 °C to 85 °C	Daik (tabes)			

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<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply.

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ABSOLUTE MAXIMUM RATINGS <sup>a</sup>				
Parameter		Limit	Unit	
Voltage on any Pin with Respect to Ground		- 0.3 to V <sub>DD</sub> + 0.3		
Voltage on Pins 5, 8 with Respect to Ground		- 1 to V <sub>DD</sub> + 1	V	
Voltage on Pins 1, 4	- 0.3 to GND + 1			
Peak Output Current		1.5	A	
Storage Temperature	- 65 to 150	°C		
Maximum Junction Temperature (T <sub>J</sub> )	150			
Maximum V <sub>DD</sub>		15	V	
Power Dissipation <sup>b</sup>		1	W	
$\Theta_{JA}$		100	°C/W	
Operating Temperature Range	Si9986CY	0 to 70	°C	
Operating reinperature harrye	Si9986DY	- 45 to 85		

#### Notes:

a. Device mounted with all leads soldered or welded to PC board. b. Derate 10 mW/°C above 25 °C.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE				
Parameter	Limit	Unit		
V <sub>DD</sub>	3.8 to 13.2	V		
Maximum Junction Temperature (T <sub>J</sub> )	125	°C		

SPECIFICATIONS								
		Test Conditions Unless Otherwise Specified V <sub>DD</sub> = 3.8 to 13.2 V		Limits C Suffix, 0 °C to 70 °C D Suffix, - 40 °C to 85 °C				
Parameter	Symbol	S <sub>A</sub> at GND, S <sub>B</sub> at GND		Min <sup>a</sup>	Typ <sup>b</sup>	Max <sup>a</sup>	Unit	
Input								
Input Voltage High	$V_{INH}$			2			V	
Input Voltage Low	$V_{INL}$					1	v	
Input Current with Input Voltage High	I <sub>INH</sub>	$V_{IN} = 2$	2 V			1	μΑ	
Input Current with Input Voltage Low	I <sub>INL</sub>	$V_{IN} = 0$	) V	- 1			μΑ	
Output								
		I <sub>OUT</sub> = - 500 mA	$V_{DD} = 10.8 \text{ V}$	10.5	10.7			
Output Voltage High	V <sub>OUTH</sub>		$V_{DD} = 4.5 \text{ V}$	4.1	4.3			
		I <sub>OUT</sub> = - 300 mA	I <sub>OUT</sub> = - 300 mA, V <sub>DD</sub> = 3.8 V		3.7		v	
	V <sub>OUTL</sub>	I <sub>OUT</sub> = 500 mA	$V_{DD} = 10.8 \text{ V}$		0.2	0.3	]	
Output Voltage Low			$V_{DD} = 4.5 \text{ V}$		0.2	0.4		
		$I_{OUT} = 300 \text{ mA},$	$V_{DD} = 3.8 \text{ V}$		0.1	0.4		
Output Leakage Current High	I <sub>OLH</sub>	$IN_A = IN_B \ge 2 \text{ V}, V_{OU}$	<sub>T</sub> = V <sub>DD</sub> = 13.2 V	- 10	0		μΑ	
Output Leakage Current Low	I <sub>OLL</sub>	$V_{OUT} = 0, V_{DI}$	<sub>D</sub> = 13.2 V		0	10	μΑ	
Output V Clamp High	$V_{CLH}$	$IN_A = IN_B \ge 2 \text{ V}$	I <sub>OUT</sub> = 100 mA		$V_{DD} + 0.7$		V	
Output V Clamp Low	$V_{CLL}$	11.4¥ – 11.4B ≂ 5. A	I <sub>OUT</sub> = - 100 mA		- 0.7		]	
Supply								
V <sub>DD</sub> Supply Current	I <sub>DD</sub>	$IN = 100 \text{ kHz}, V_{DD} = 5 \text{ V}$			2		mA	
V <sub>DD</sub> Cappiy Current	טטי	$IN_A = IN_B = 4.5 \text{ V}, V_{DD} = 5.5 \text{ V}$				300	μΑ	
Dynamic								
Propogation Delay Time	$T_PLH$	V <sub>DD</sub> = 5 V			300		nS	
1 Topogation Delay Time	$T_{PHL}$				100		110	

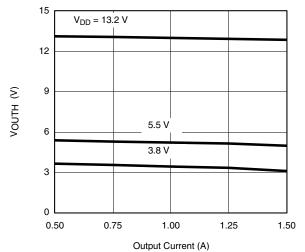
#### Notes:

a. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

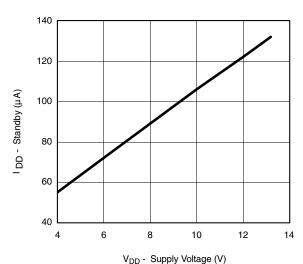
b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.



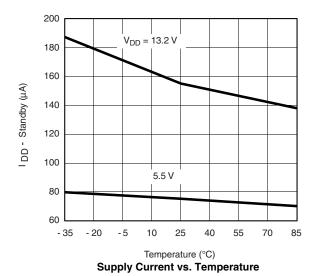
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Output High Voltage vs. Output Current



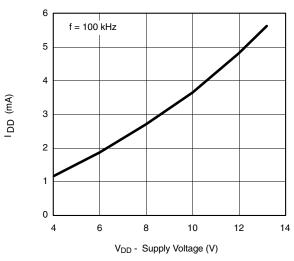
Supply Current vs. Supply Voltage



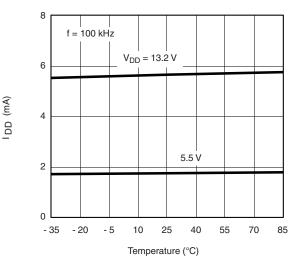
700 600 500 VOUTL (mV) 400  $V_{DD} = 3.8 \text{ V}$ 13.2 V 300 200 100 0 0.50 0.75 1.00 1.25 1.50

Output Current (A)

Output Low Voltage vs. Output Current



Supply Current vs. Supply Voltage

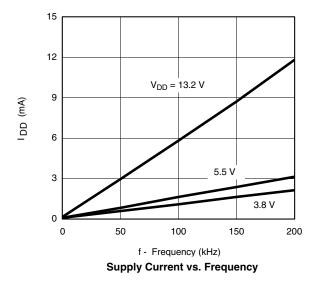


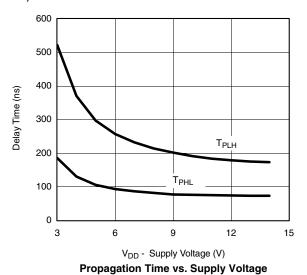
Supply Current vs. Temperature

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### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?70007.



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIMETERS INCHES		HES	
DIM	Min	Max	Min	Max
Α	1.35	1.75	0.053	0.069
A <sub>1</sub>	0.10	0.20	0.004	0.008
В	0.35	0.51	0.014	0.020
С	0.19	0.25	0.0075	0.010
D	4.80	5.00	0.189	0.196
Е	3.80	4.00	0.150	0.157
е	1.27 BSC		0.050	) BSC
Н	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.020
L	0.50	0.93	0.020	0.037
q	0°	8°	0°	8°
S	0.44	0.64	0.018	0.026
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DWG: 5498

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